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<u>Fairchild Semiconductor</u> <u>KSA1243OTU</u>

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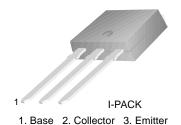




### **KSA1243**

## **Power Amplifier Applications**

• Complement to KSC3073



## **PNP Epitaxial Silicon Transistor**

## Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{CBO}$	Collector-Base Voltage	- 30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	- 30	V
V <sub>EBO</sub>	Emitter-Base Voltage	- 5	V
I <sub>B</sub>	Base Current	- 0.6	Α
I <sub>C</sub>	Collector Current	- 3	Α
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	10	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## $\textbf{Electrical Characteristics} \ \textbf{T}_{\text{C}} = 25 \text{ °C unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = - 10mA, I <sub>B</sub> = 0	- 30			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = - 1mA, I <sub>C</sub> = 0	- 5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = - 20V, I <sub>E</sub> = 0			- 1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			- 1	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = -2V, I_{C} = -0.5A$	70		240	
h <sub>FE2</sub>		$V_{CE} = -2V, I_{C} = -2.5A$	25			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -2A, I_B = -0.2A$		- 0.3	- 0.8	V
V <sub>BE</sub> (on)	Base-Emitter ON Voltage	$V_{CE} = -2V, I_{C} = -0.5A$		- 0.75	- 1	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = -2V, I_{C} = -0.5A$		100		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = - 10V, f = 1MHz		40		pF

## $h_{\text{FE}}$ Classification

Classification	0	Y	
h <sub>FE1</sub>	70 ~ 140	120 ~ 240	

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## **Typical Characteristics**

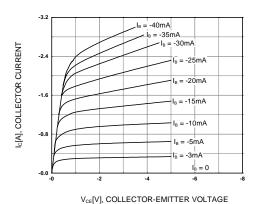


Figure 1. Static Characteristic

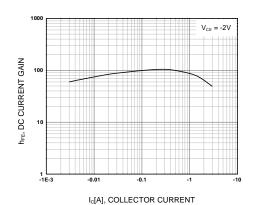


Figure 2. DC current Gain

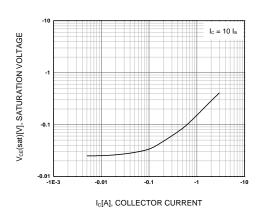


Figure 3. Collector-Emitter Saturation Votlage

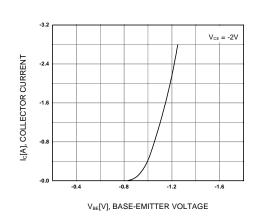


Figure 4. Base-Emitter On Voltage

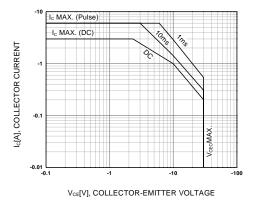


Figure 5. Safe Operating Area

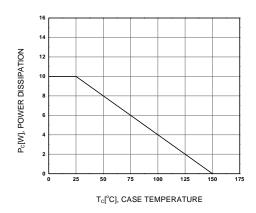


Figure 6. Power Derating

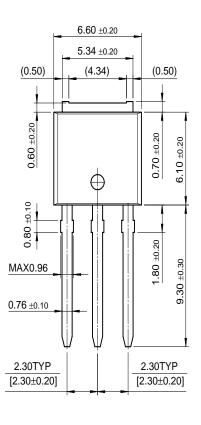
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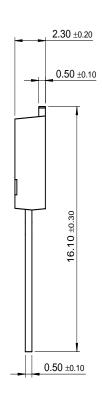
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**Package Demensions** 

# I-PAK





Dimensions in Millimeters



## Distributor of Fairchild Semiconductor: Excellent Integrated System Limited

Datasheet of KSA1243OTU - TRANS PNP 30V 3A I-PAK

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